Low-power 2-input NAND gate Rev. 6 — 27 June 2012

Product data sheet

General description 1.

The 74AUP1G00 provides the single 2-input NAND function.

Schmitt-trigger action at all inputs makes the circuit tolerant to slower input rise and fall times across the entire V_{CC} range from 0.8 V to 3.6 V.

This device ensures a very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V.

This device is fully specified for partial Power-down applications using I_{OFF}. The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

2. **Features and benefits**

- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- Complies with JEDEC standards:
 - JESD8-12 (0.8 V to 1.3 V)
 - JESD8-11 (0.9 V to 1.65 V)
 - JESD8-7 (1.2 V to 1.95 V)
 - JESD8-5 (1.8 V to 2.7 V)
 - JESD8-B (2.7 V to 3.6 V)
- ESD protection:
 - HBM JESD22-A114F Class 3A exceeds 5000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101E exceeds 1000 V
- Low static power consumption; $I_{CC} = 0.9 \,\mu A$ (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- I_{OFF} circuitry provides partial Power-down mode operation
- Multiple package options
- Specified from –40 °C to +85 °C and –40 °C to +125 °C

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3. Ordering information

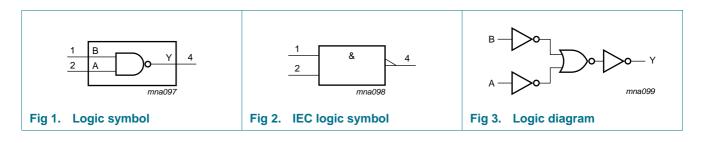
Type number	Package	Package						
	Temperature range	Name	Description	Version				
74AUP1G00GW	–40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads; body width 1.25 mm	SOT353-1				
74AUP1G00GM	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 \times 1.45 \times 0.5 mm	SOT886				
74AUP1G00GF	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 \times 1 \times 0.5 mm	SOT891				
74AUP1G00GN	–40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body $0.9 \times 1.0 \times 0.35$ mm	SOT1115				
74AUP1G00GS	–40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body $1.0 \times 1.0 \times 0.35$ mm	SOT1202				
74AUP1G00GX	–40 °C to +125 °C	X2SON5	X2SON5: plastic thermal enhanced extremely thin small outline package; no leads; 5 terminals; body $0.8 \times 0.8 \times 0.35$ mm	SOT1226				

4. Marking

Table 2. Marking	
Type number	Marking code ^[1]
74AUP1G00GW	рА
74AUP1G00GM	рА
74AUP1G00GF	рА
74AUP1G00GN	рА
74AUP1G00GS	рА
74AUP1G00GX	рА

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

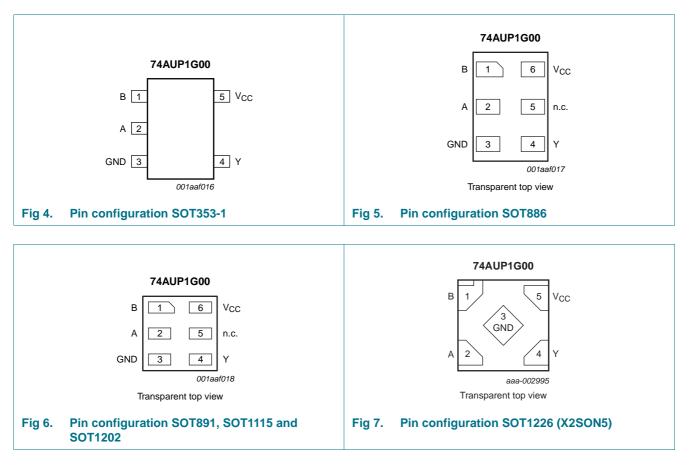
5. Functional diagram



74AUP1G00 Product data sheet

6. Pinning information

6.1 Pinning



6.2 Pin description

SymbolPinDescriptionTSSOP5 and X2SON5XSON6B11A22GND33Y44n.c5V _{CC} 56	Table 3. P	in description		
B1data inputA22data inputGND33ground (0 V)Y44data outputn.c5not connected	Symbol	Pin		Description
A 2 data input GND 3 3 ground (0 V) Y 4 4 data output n.c. - 5 not connected		TSSOP5 and X2SON5	XSON6	
GND33ground (0 V)Y44data outputn.c5not connected	В	1	1	data input
Y44data outputn.c5not connected	A	2	2	data input
n.c 5 not connected	GND	3	3	ground (0 V)
	Y	4	4	data output
V _{CC} 5 6 supply voltage	n.c.	-	5	not connected
	V _{CC}	5	6	supply voltage

7. Functional description

Table 4.	Function table ^[1]	
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Input		Output
Α	В	Y
L	L	Н
L	Н	Н
Н	L	Н
Н	Н	L

[1] H = HIGH voltage level; L = LOW voltage level.

8. Limiting values

Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+4.6	V
I _{IK}	input clamping current	V ₁ < 0 V	-50	-	mA
VI	input voltage		<u>[1]</u> –0.5	+4.6	V
Ι _{ΟΚ}	output clamping current	V _O < 0 V	-50	-	mA
Vo	output voltage	Active mode	<u>[1]</u> –0.5	$V_{CC} + 0.5$	V
		Power-down mode	<u>[1]</u> –0.5	+4.6	V
I _O	output current	$V_{O} = 0 V$ to V_{CC}	-	±20	mA
I _{CC}	supply current		-	+50	mA
I _{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 \ ^{\circ}C$ to +125 $^{\circ}C$	[2] _	250	mW

[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

For TSSOP5 packages: above 87.5 °C the value of P_{tot} derates linearly with 4.0 mW/K.
 For XSON6 and X2SON5 packages: above 118 °C the value of P_{tot} derates linearly with 7.8 mW/K.

9. Recommended operating conditions

Table 6.	Recommended operating conditions						
Symbol	Parameter	Conditions	Min	Max	Unit		
V _{CC}	supply voltage		0.8	3.6	V		
VI	input voltage		0	3.6	V		
Vo	output voltage	Active mode	0	V _{CC}	V		
		Power-down mode; $V_{CC} = 0 V$	0	3.6	V		
T _{amb}	ambient temperature		-40	+125	°C		
$\Delta t / \Delta V$	input transition rise and fall rate	V_{CC} = 0.8 V to 3.6 V	0	200	ns/V		

10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	5 °C					
V _{IH}	HIGH-level input voltage	$V_{CC} = 0.8 V$	$0.70 \times V_{CC}$	-	-	V
		$V_{CC} = 0.9 V$ to 1.95 V	$0.65 \times V_{CC}$	-	-	V
		V_{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	2.0	-	-	V
V _{IL}	LOW-level input voltage	$V_{CC} = 0.8 V$	-	-	$0.30 \times V_{CC}$	V
		$V_{CC} = 0.9 V$ to 1.95 V	-	-	$0.35 \times V_{CC}$	V
		V_{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	-	-	0.9	V
V _{OH}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = –20 $\mu A;$ V_{CC} = 0.8 V to 3.6 V	$V_{CC} - 0.1$	-	-	V
		$I_0 = -1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$	$0.75 \times V_{CC}$	-	-	V
		$I_0 = -1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$	1.11	-	-	V
		$I_{O} = -1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$	1.32	-	-	V
		$I_0 = -2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	2.05	-	-	V
		$I_0 = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.9	-	-	V
		$I_0 = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.72	-	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.6	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = 20 $\mu A; V_{CC}$ = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	$0.3 \times V_{CC}$	V
		$I_0 = 1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$	-	-	0.31	V
		$I_0 = 1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$	-	-	0.31	V
		$I_0 = 2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.31	V
		$I_0 = 3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.44	V
		$I_0 = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.31	V
		$I_0 = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.44	V
l	input leakage current	$V_I = GND$ to 3.6 V; $V_{CC} = 0$ V to 3.6 V	-	-	±0.1	μΑ
I _{OFF}	power-off leakage current	V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	±0.2	μΑ
ΔI_{OFF}	additional power-off leakage current	V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V	-	-	±0.2	μΑ
lcc	supply current	$\label{eq:VI} \begin{array}{l} V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \; A; \\ V_{CC} = 0.8 \; V \; to \; 3.6 \; V \end{array}$	-	-	0.5	μΑ
Δl _{CC}	additional supply current		<u>[1]</u> -	-	40	μΑ
Cı	input capacitance	$V_{CC} = 0$ V to 3.6 V; $V_{I} = GND$ or V_{CC}	-	0.8	-	pF
Co	output capacitance	$V_{O} = GND; V_{CC} = 0 V$	-	1.7	-	pF

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
-	40 °C to +85 °C			71		
VIH	HIGH-level input voltage	V _{CC} = 0.8 V	$0.70 \times V_{CC}$	-	-	V
		$V_{CC} = 0.9 \text{ V to } 1.95 \text{ V}$	$0.65 \times V_{CC}$		-	V
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.6	-	-	V
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 0.8 V	-	-	$0.30 imes V_{CC}$	V
		$V_{CC} = 0.9 \text{ V} \text{ to } 1.95 \text{ V}$	-	-	$0.35 imes V_{CC}$	
		V_{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	-	-	0.9	V
V _{ОН}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = -20 μ A; V_{CC} = 0.8 V to 3.6 V	$V_{CC} - 0.1$	-	-	V
		$I_{O} = -1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$	$0.7 imes V_{CC}$	-	-	V
		$I_{O} = -1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$	1.03	-	-	V
		$I_{O} = -1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$	1.30	-	-	V
		$I_{O} = -2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.97	-	-	V
		$I_{O} = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.85	-	-	V
		$I_{O} = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.67	-	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.55	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_O = 20 $\mu A; V_{CC}$ = 0.8 V to 3.6 V	-	-	0.1	V
		I_{O} = 1.1 mA; V_{CC} = 1.1 V	-	-	$0.3 \times V_{CC}$	V
		I_{O} = 1.7 mA; V_{CC} = 1.4 V	-	-	0.37	V
		I_{O} = 1.9 mA; V_{CC} = 1.65 V	-	-	0.35	V
		I_{O} = 2.3 mA; V_{CC} = 2.3 V	-	-	0.33	V
		I_{O} = 3.1 mA; V_{CC} = 2.3 V	-	-	0.45	V
		I_{O} = 2.7 mA; V_{CC} = 3.0 V	-	-	0.33	V
		I_{O} = 4.0 mA; V_{CC} = 3.0 V	-	-	0.45	V
l _l	input leakage current	$V_{\rm I}$ = GND to 3.6 V; $V_{\rm CC}$ = 0 V to 3.6 V	-	-	±0.5	μΑ
I _{OFF}	power-off leakage current	$V_{\rm I}~{\rm or}~V_{\rm O}$ = 0 V to 3.6 V; $V_{\rm CC}$ = 0 V	-	-	±0.5	μΑ
ΔI_{OFF}	additional power-off leakage current	$V_{I} \text{ or } V_{O} = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.6	μΑ
I _{CC}	supply current	$\label{eq:VI} \begin{array}{l} V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \; A; \\ V_{CC} = 0.8 \; V \; \mathrm{to} \; 3.6 \; V \end{array}$	-	-	0.9	μΑ
ΔI_{CC}	additional supply current	$V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0 \text{ A};$ $V_{CC} = 3.3 \text{ V}$	<u>[1]</u> -	-	50	μΑ

Table 7. Static characteristics ...continued

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = –	40 °C to +125 °C					
V _{IH}	HIGH-level input voltage	$V_{CC} = 0.8 V$	$0.75 \times V_{CC}$	-	-	V
		$V_{CC} = 0.9 V$ to 1.95 V	$0.70\times V_{CC}$	-	-	V
		V_{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	2.0	-	-	V
V _{IL}	LOW-level input voltage	$V_{CC} = 0.8 V$	-	-	$0.25 \times V_{CC}$	V
		$V_{CC} = 0.9 V$ to 1.95 V	-	-	$0.30 \times V_{CC}$	V
		V_{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	-	-	0.9	V
V _{он}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = –20 $\mu\text{A};~V_{CC}$ = 0.8 V to 3.6 V	$V_{CC} - 0.11$	-	-	V
	$I_{O} = -1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$	$0.6 imes V_{CC}$	-	-	V	
		$I_{O} = -1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$	0.93	-	-	V
		$I_{O} = -1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$	1.17	-	-	V
		$I_{O} = -2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.77	-	-	V
		$I_{O} = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.67	-	-	V
		$I_{O} = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.40	-	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.30	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_O = 20 $\mu A; V_{CC}$ = 0.8 V to 3.6 V	-	-	0.11	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	$0.33 \times V_{CC}$	V
		I_{O} = 1.7 mA; V_{CC} = 1.4 V	-	-	0.41	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.39	V
		I_{O} = 2.3 mA; V_{CC} = 2.3 V	-	-	0.36	V
		I_{O} = 3.1 mA; V_{CC} = 2.3 V	-	-	0.50	V
		I_{O} = 2.7 mA; V_{CC} = 3.0 V	-	-	0.36	V
		I_{O} = 4.0 mA; V_{CC} = 3.0 V	-	-	0.50	V
l _l	input leakage current	V_I = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.75	μΑ
I _{OFF}	power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.75	μΑ
Δl _{OFF}	additional power-off leakage current	$V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.75	μΑ
lcc	supply current	$\label{eq:VI} \begin{array}{l} V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \; A; \\ V_{CC} = 0.8 \; V \; to \; 3.6 \; V \end{array}$	-	-	1.4	μΑ
ΔI _{CC}	additional supply current	$V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0 \text{ A};$ $V_{CC} = 3.3 \text{ V}$	<u>[1]</u> -	-	75	μΑ

Table 7. Static characteristics ...continued

[1] One input at V_{CC} – 0.6 V, other input at V_{CC} or GND.

11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 9

Symbol	Parameter	Conditions		Min	Typ 🛄	Max	Unit
T _{amb} = 25	°C; C _L = 5 pF						
t _{pd}	propagation delay	A, B to Y; see Figure 8	[2]				
		$V_{CC} = 0.8 V$		-	17.5	-	ns
		V_{CC} = 1.1 V to 1.3 V		2.5	5.3	11.0	ns
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$		2.0	3.8	6.8	ns
		V_{CC} = 1.65 V to 1.95 V		1.6	3.1	5.3	ns
		V_{CC} = 2.3 V to 2.7 V		1.3	2.5	4.0	ns
		V_{CC} = 3.0 V to 3.6 V		1.0	2.2	3.6	ns
T _{amb} = 25	°C; C _L = 10 pF						
t _{pd}	propagation delay	A, B to Y; see Figure 8	[2]				
		$V_{CC} = 0.8 V$		-	21.0	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		2.4	6.1	13.0	ns
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$		2.4	4.4	7.9	ns
		V_{CC} = 1.65 V to 1.95 V		2.0	3.7	6.2	ns
		V_{CC} = 2.3 V to 2.7 V		1.4	3.0	4.7	ns
		V_{CC} = 3.0 V to 3.6 V		1.3	2.8	4.3	ns
T _{amb} = 25	°C; C _L = 15 pF						
t _{pd}	propagation delay	A, B to Y; see Figure 8	[2]				
		$V_{CC} = 0.8 V$		-	24.5	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		3.4	6.9	14.8	ns
		$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$		2.8	5.0	8.9	ns
		V_{CC} = 1.65 V to 1.95 V		2.0	4.1	7.0	ns
		V_{CC} = 2.3 V to 2.7 V		1.7	3.5	5.3	ns
		V_{CC} = 3.0 V to 3.6 V		1.6	3.2	4.9	ns
T _{amb} = 25	°C; C _L = 30 pF						
t _{pd}	propagation delay	A, B to Y; see Figure 8	[2]				
		$V_{CC} = 0.8 V$		-	34.8	-	ns
		V_{CC} = 1.1 V to 1.3 V		4.6	9.2	20.1	ns
		V_{CC} = 1.4 V to 1.6 V		3.0	6.5	11.8	ns
		V_{CC} = 1.65 V to 1.95 V		2.6	5.4	9.3	ns
		V_{CC} = 2.3 V to 2.7 V		2.4	4.6	7.1	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		2.3	4.3	6.5	ns

Low-power 2-input NAND gate

Symbol	Parameter	Conditions	Min	Typ 🚹	Max	Unit
T _{amb} = 25	°C					
C _{PD}	power dissipation capacitance	$f = 1 \text{ MHz}; V_I = \text{GND to } V_{CC}$ [3]				
		$V_{CC} = 0.8 V$	-	2.6	-	pF
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$	-	2.8	-	pF
		$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$	-	2.9	-	pF
		$V_{CC} = 1.65 \text{ V} \text{ to } 1.95 \text{ V}$	-	3.1	-	pF
		V_{CC} = 2.3 V to 2.7 V	-	3.6	-	pF
		V _{CC} = 3.0 V to 3.6 V	-	4.2	-	pF

Table 8. Dynamic characteristics ... continued

[1] All typical values are measured at nominal V_{CC} .

[2] t_{pd} is the same as t_{PLH} and t_{PHL} .

[3] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W).

 $P_{D} = C_{PD} \times V_{CC}{}^{2} \times f_{i} \times N + \Sigma (C_{L} \times V_{CC}{}^{2} \times f_{o}) \text{ where:}$

 f_i = input frequency in MHz;

 $f_o = output frequency in MHz;$

C_L = output load capacitance in pF;

 V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

Table 9. **Dynamic characteristics**

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 9

Symbol	Parameter	Conditions		–40 °C to +85 °C		–40 °C to +125 °C		Unit
				Min	Max	Min	Max	
C _L = 5 pF								
t _{pd}	propagation delay	A, B to Y; see Figure 8	<u>[1]</u>					
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		2.1	12.2	2.1	13.5	ns
		V_{CC} = 1.4 V to 1.6 V		1.8	7.8	1.8	8.6	ns
		V_{CC} = 1.65 V to 1.95 V		1.4	6.2	1.4	6.9	ns
		V_{CC} = 2.3 V to 2.7 V		1.1	4.7	1.1	5.2	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		1.0	4.2	1.0	4.7	ns
C _L = 10 p	F							
t _{pd}	propagation delay	A, B to Y; see Figure 8	<u>[1]</u>					
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		2.2	14.4	2.2	15.9	ns
		$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$		2.2	9.2	2.2	10.2	ns
		V_{CC} = 1.65 V to 1.95 V		1.9	7.3	1.9	8.1	ns
		V_{CC} = 2.3 V to 2.7 V		1.3	5.6	1.3	6.2	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		1.2	4.9	1.2	5.4	ns

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Symbol	Parameter	Conditions		–40 °C to +85 °C		–40 °C to +125 °C		Unit
				Min	Max	Min	Max	
C _L = 15 p	F				1			
t _{pd}	propagation delay	A, B to Y; see Figure 8	<u>[1]</u>					
		$V_{CC} = 1.1 \text{ V}$ to 1.3 V		3.1	16.5	3.1	18.2	ns
		$V_{CC} = 1.4 \text{ V}$ to 1.6 V		2.5	10.5	2.5	11.6	ns
		V_{CC} = 1.65 V to 1.95 V		2.0	8.3	2.0	9.2	ns
		V_{CC} = 2.3 V to 2.7 V		1.5	6.4	1.5	7.1	ns
		V_{CC} = 3.0 V to 3.6 V		1.4	5.7	1.4	6.3	ns
C _L = 30 p	F							
t _{pd}	propagation delay	A, B to Y; see Figure 8	<u>[1]</u>					
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		4.1	22.6	4.1	24.9	ns
		$V_{CC} = 1.4 \text{ V}$ to 1.6 V		2.9	14.0	2.9	15.4	ns
		V_{CC} = 1.65 V to 1.95 V		2.3	11.1	2.3	12.3	ns
		V_{CC} = 2.3 V to 2.7 V		2.1	8.5	2.1	9.4	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		2.1	7.6	2.1	8.4	ns

Dynamic characteristics ... continued Table 9. 010

[1] t_{pd} is the same as t_{PLH} and t_{PHL} .

12. Waveforms

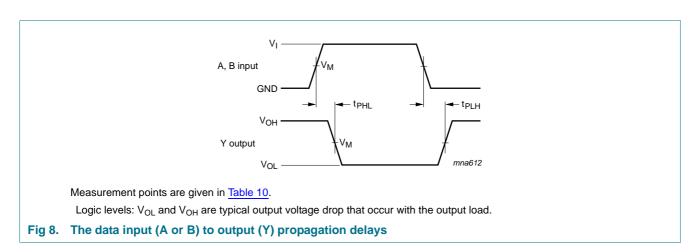


Table 10. Measurement points

Supply voltage	Output	Input		
V _{cc}	V _M	V _M	VI	$t_r = t_f$
0.8 V to 3.6 V	$0.5 \times V_{CC}$	$0.5 imes V_{CC}$	V _{CC}	\leq 3.0 ns

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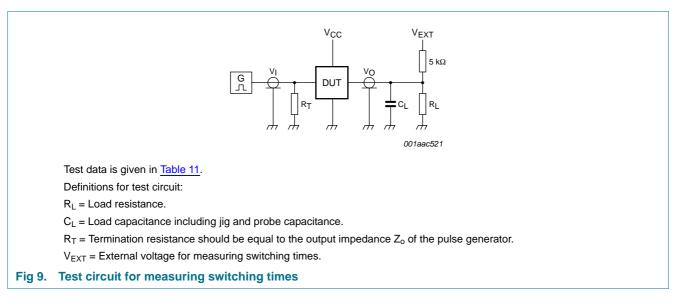


Table 11. Test data

Supply voltage	Load		V _{EXT}		
V _{CC}	CL	R _L [1]	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 k Ω or 1 M Ω	open	GND	$2 \times V_{CC}$

[1] For measuring enable and disable times $R_L = 5 k\Omega$, for measuring propagation delays, setup and hold times and pulse width $R_L = 1 M\Omega$.

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13. Package outline

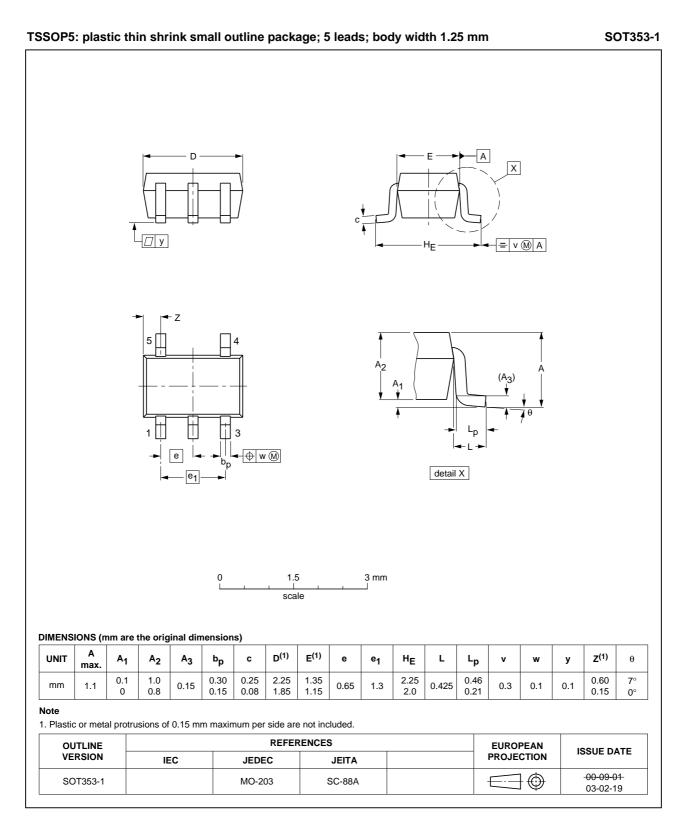
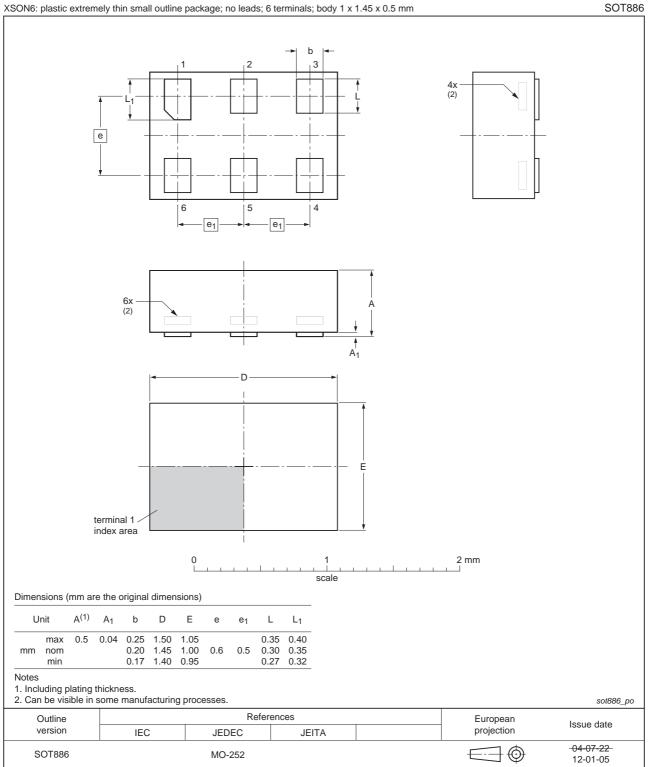


Fig 10. Package outline SOT353-1 (TSSOP5)

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XSON6: plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1.45 x 0.5 mm

Fig 11. Package outline SOT886 (XSON6)

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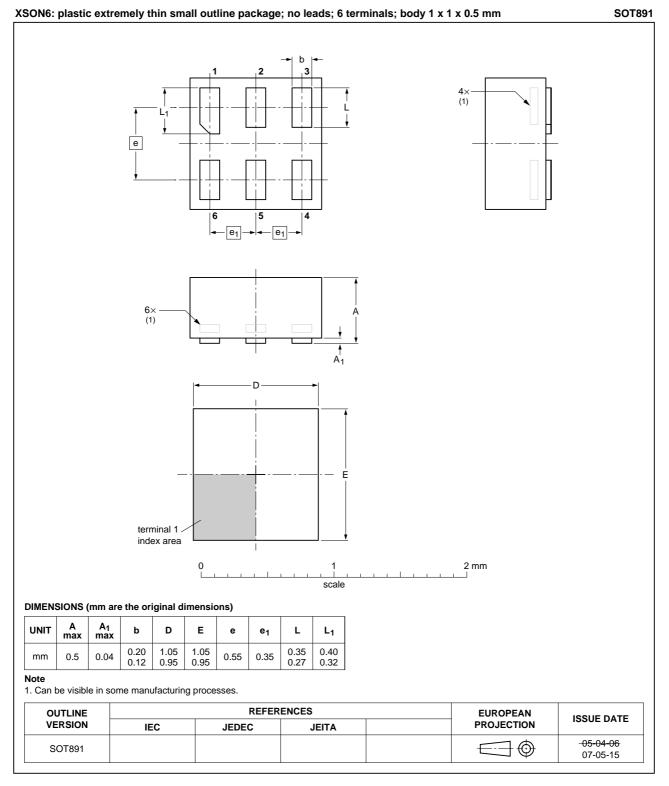
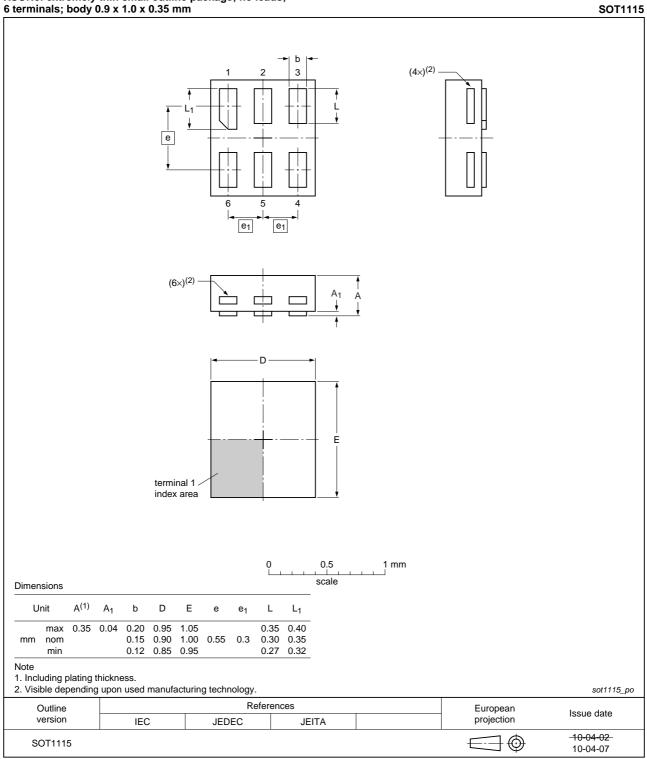


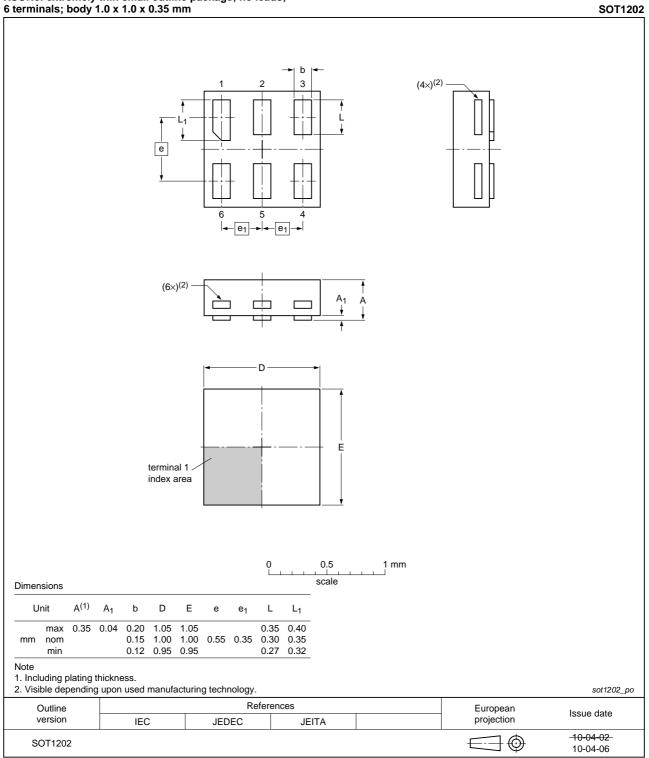
Fig 12. Package outline SOT891 (XSON6)

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XSON6: extremely thin small outline package; no leads; 6 terminals; body 0.9 x 1.0 x 0.35 mm

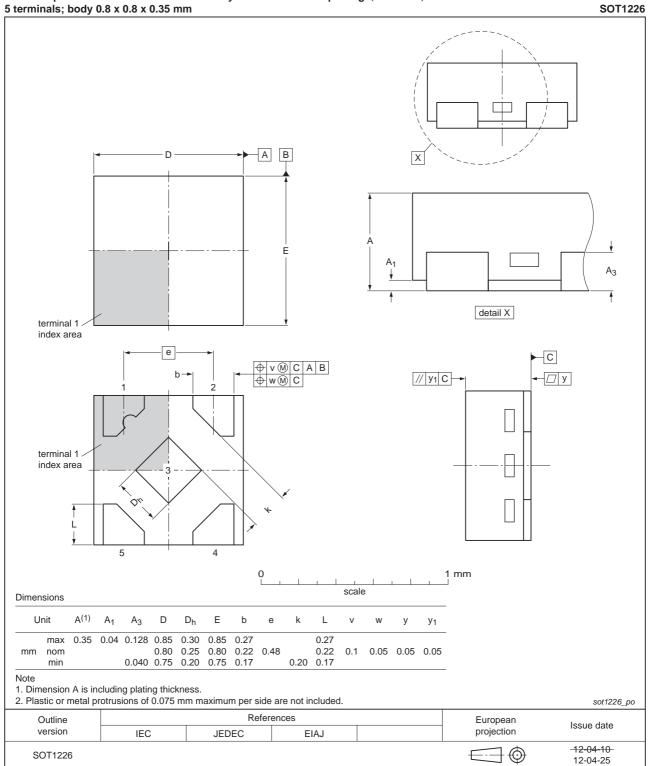
Fig 13. Package outline SOT1115 (XSON6)



XSON6: extremely thin small outline package; no leads; 6 terminals; body 1.0 x 1.0 x 0.35 mm

Fig 14. Package outline SOT1202 (XSON6)

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X2SON5: plastic thermal enhanced extremely thin small outline package; no leads; 5 terminals; body 0.8 x 0.8 x 0.35 mm

Fig 15. Package outline SOT1226 (X2SON5)

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14. Abbreviations

	bbreviations
Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model

15. Revision history

history			
Release date	Data sheet status	Change notice	Supersedes
20120627	Product data sheet	-	74AUP1G00 v.5
 Added type nur 	nber 74AUP1G00GX (SOT1226	s).	
20120316	Product data sheet	-	74AUP1G00 v.4
 Package outline 	e drawing of SOT886 (<mark>Figure 11</mark>) modified.	
20111115	Product data sheet	-	74AUP1G00 v.3
 Legal pages up 	dated.		
20101007	Product data sheet	-	74AUP1G00 v.2
20060629	Product data sheet	-	74AUP1G00 v.1
20050711	Product data sheet	-	-
	20120627 • Added type nur 20120316 • Package outline 20111115 • Legal pages up 20101007 20060629	20120627Product data sheet• Added type number 74AUP1G00GX (SOT1226)20120316Product data sheet• Package outline drawing of SOT886 (Figure 11)20111115Product data sheet• Legal pages updated.20101007Product data sheet20060629Product data sheet	20120627Product data sheet-• Added type number 74AUP1G00GX (SOT1226).20120316Product data sheet-• Package outline drawing of SOT886 (Figure 11) modified.20111115Product data sheet-• Legal pages updated.20101007Product data sheet-20060629Product data sheet-

16. Legal information

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Document status[1][2]	Product status ^[3]	Definition
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Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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